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FDD86580-F085

N-Channel PowerTrench[®] MOSFET **60 V, 50 A, 10 m**Ω

Features

- Typical $R_{DS(on)}$ = 7.8 mΩ at V_{GS} = 10V, I_D = 50 A
- Typical Q_{g(tot)} = 20 nC at V_{GS} = 10V, I_D = 50 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Electronic Steering
- Integrated Starter/Alternator
- Distributed Power Architectures and VRM

Primary Switch for 12V Systems

MOSFET Maximum Ratings T_J = 25°C unless otherwise noted.

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain-to-Source Voltage		60	V
V _{GS}	Gate-to-Source Voltage		±20	V
	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	50	•
D	Pulsed Drain Current	T _C = 25°C	See Figure 4	Α
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	24	mJ
D	Power Dissipation		75	W
P _D	Derate Above 25°C		0.5	W/ ^o C
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case		2.0	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	52	°C/W

Notes:

- 1: Current is limited by bondwire configuration.

ROHS

G

S

2: Starting T_J = 25°C, L = 30µH, I_{AS} = 40A, V_{DD} = 60V during inductor charging and V_{DD} = 0V during time in avalanche. 3: R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design, while R_{0JA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD86580	FDD86580-F085	D-PAK(TO-252)	13"	16mm	2500units

FDD86580-F085 N-Channel PowerTrench[®] MOSFET

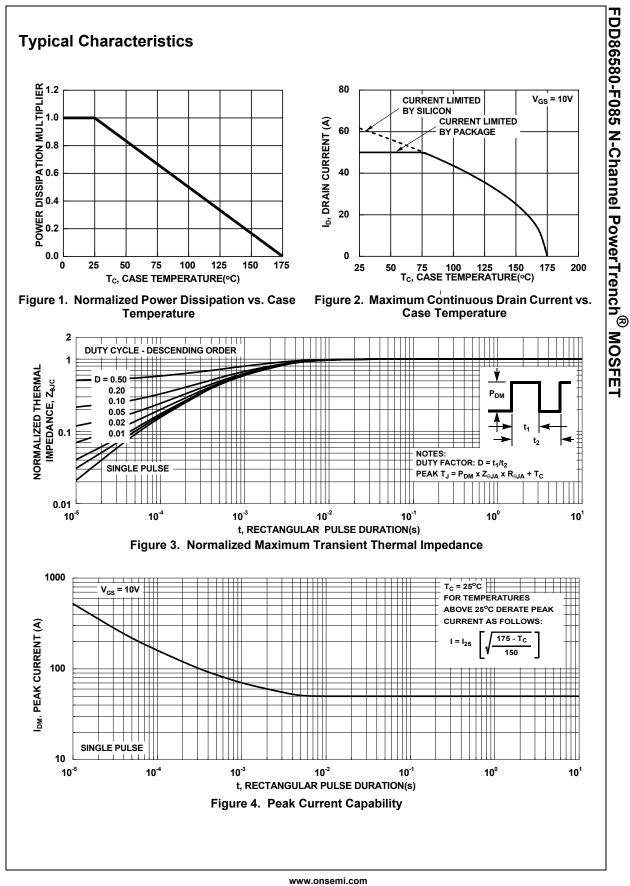
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D-PAK

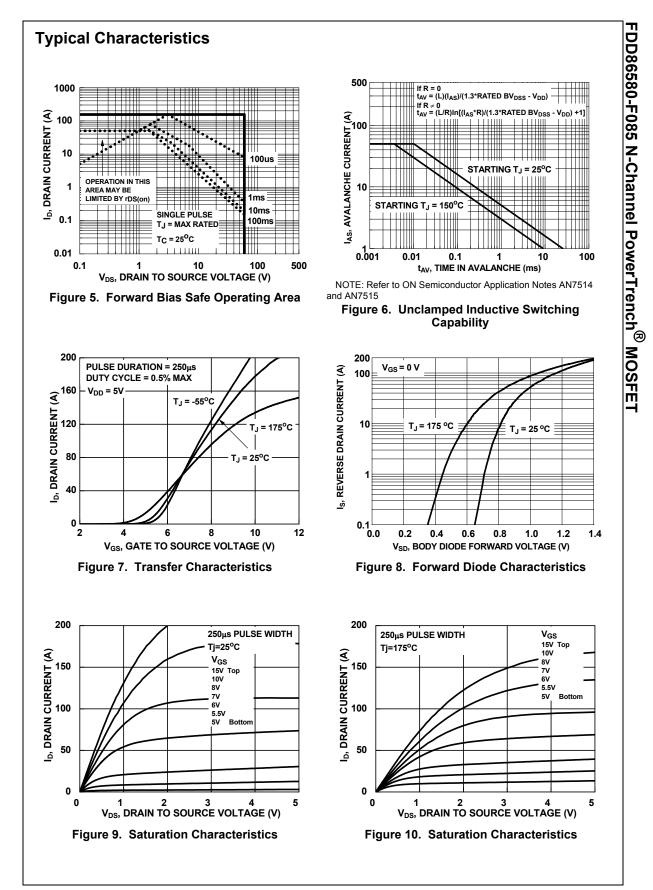
(TO-252)

	Parameter	Test Conditions		Min.	Тур.	Max.	Units
Off Cha	racteristics						
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA,	V _{GS} = 0V	60	-	-	V
	V _{DS} =6		$T_{\rm J} = 25^{\circ} C$		-	1	μA
IDSS	Drain-to-Source Leakage Current	$V_{GS} = 0V$	$T_{\rm J} = 175^{\rm o}C$ (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA
On Cha	racteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250µA		2.0	3.6	4.2	V
		$I_{\rm D} = 50$ A, $T_{\rm J} = 25^{\circ}$ C		-	7.8	10	mΩ
R _{DS(on)}	Drain to Source On Resistance		$T_{.1} = 175^{\circ}C$ (Note 4)	-	15.2	19	mΩ
C _{iss}	Input Capacitance	V _{DS} = 30V, V _{GS} = 0V, f = 1MHz		-	1430	-	pF
C _{oss}	Output Capacitance			-	440	-	pF
C _{rss}	Reverse Transfer Capacitance			-	25	-	pF
R _g	Gate Resistance	V _{GS} = 0.5V, f = 1MHz		-	1.8	-	Ω
Q _{g(ToT)}	Total Gate Charge	$V_{GS} = 0$ to 10V $V_{DD} = 30V$		-	20	30	nC
Q _{g(th)}	Threshold Gate Charge	V_{GS} = 0 to 2	V I _D = 50A	-	3	-	nC
Q _{gs}	Gate-to-Source Gate Charge		_	-	9	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge			-	4	-	nC
Switchi	ng Characteristics						
t _{on}	Turn-On Time			-	-	34	ns
t _{d(on)}	Turn-On Delay			-	12	-	ns
t _r	Rise Time	V _{DD} = 30V,	I _D = 50A,	-	11	-	ns
t _{d(off)}	Turn-Off Delay	V_{GS} = 10V, R_{GEN} = 6 Ω		-	15	-	ns
t _f	Fall Time			-	5	-	ns
t _{off}	Turn-Off Time			-	-	30	ns
	ource Diode Characteristics						
Drain-S		I _{SD} = 50A, V		-	-	1.25	V
	Source-to-Drain Diode Voltage	I _{SD} = 25A, V _{GS} = 0V		-	-	1.2	V
V _{SD}	Source-to-Drain Diode Voltage	-					
	Source-to-Drain Diode Voltage Reverse-Recovery Time Reverse-Recovery Charge	$I_{SD} = 25A, V_{DD} = 48V, dI_{SD}/dt = 100$	I _F = 50A,	-	41 30	61 45	ns nC

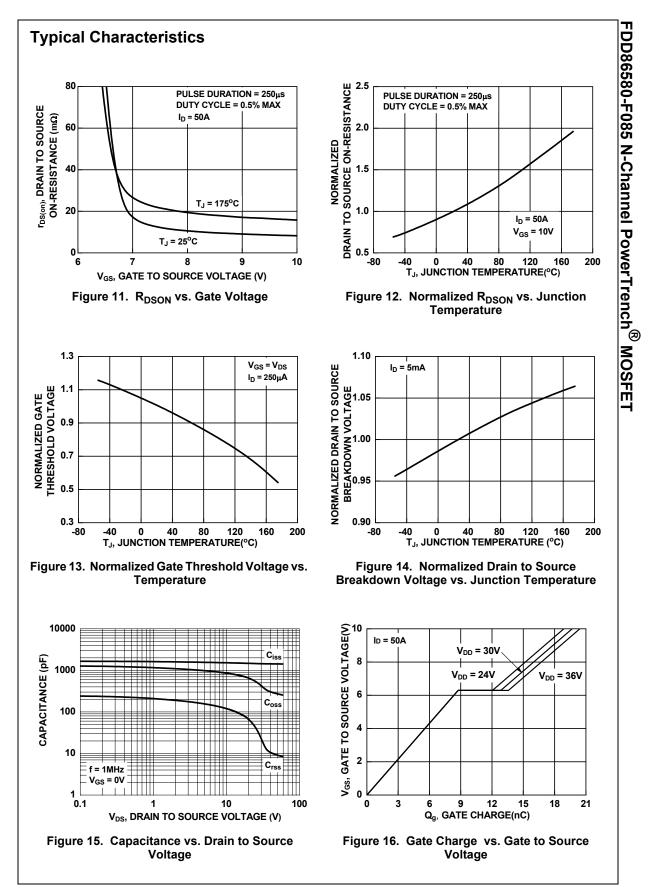
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